

## **Electronic Supplementary Information**

# **The interplay of intermolecular interactions, packing motifs and electron transport properties in perylene diimide related materials: A theoretical perspective**

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**Table S1** The crystal structures, the experimental electron mobilities ( $\mu_{\text{exp}}$ ) and their calculation values of all compounds listed in Fig. 1.

Compound	$\mu_{\text{cal.}}$ ( $\text{cm}^2/\text{V.s}$ )	$\mu_{\text{exp.}}^{\text{c}}$ ( $\text{cm}^2/\text{V.s}$ )	Cell parameters (a, b, c in Å; $\alpha, \beta, \gamma$ in deg)	Ref.
<b>1</b>	—	—	4.87; 14.66; 10.84; 90; 91.33; 90	1
<b>2</b>	0.1 <sup>a</sup>	0.10 <sup>(Ref.1)</sup>	4.75; 8.48; 16.30; 86.88; 83.50; 83.68	2
<b>3</b>	—	1.7 <sup>(Ref. 3)</sup>	4.68; 8.50; 19.72; 85.99; 88.43; 82.79	4
<b>4</b>	0.37 <sup>b</sup>	0.72 <sup>(Ref.5)</sup>	4.91; 8.48; 16.29; 97.49; 94.37; 98.03	6
<b>5</b>	—	—	4.71; 15.00; 18.59; 109.72; 95.74; 92.82	7
<b>6</b>	—	—	21.23; 15.89; 6.93; 90; 90; 90	8
<b>7</b>	0.4 <sup>a</sup>	—	28.68; 4.47; 22.10; 90; 103.12; 90	9
<b>8</b>	0.5 <sup>a</sup>	—	4.26; 10.086; 17.346; 103.84; 92.42; 100.19	9
<b>9</b>	—	10.8 <sup>(Ref. 10)</sup>	5.23; 7.64; 18.82; 92.51; 95.25; 104.73	11
<b>10</b>	1.49 <sup>b</sup>	0.58 <sup>(Ref. 6)</sup>	17.46; 5.28; 15.28; 90; 110.897; 90	12
<b>11</b>	0.99 <sup>b</sup>	0.05 <sup>(Ref. 6)</sup>	9.20; 10.97; 14.92; 87.48; 88.09; 75.62	6
<b>12</b>	0.003 <sup>b</sup>	0.0005 <sup>(Ref. 6)</sup>	27.06; 7.07; 26.32; 90; 114.67; 90	6
<b>13</b>	0.025 <sup>b</sup>	0.0003 <sup>(Ref. 6)</sup>	27.86; 7.19; 13.01; 90; 115.18; 90	6
<b>14</b>	—	0.05 <sup>(Ref. 13)</sup>	11.60; 3.73; 28.06; 90; 96.65; 90	13
<b>15</b>	—	0.14 <sup>(Ref. 13)</sup>	4.95; 9.48; 13.06; 82.16; 81.68; 87.06	13
<b>16</b>	0.34 <sup>b</sup>	0.91 <sup>(Ref. 14)</sup>	14.46; 7.36; 20.03; 90; 90; 90	14

<sup>a</sup> Calculated electron mobilities in ref. 15. <sup>b</sup> Calculated electron mobilities in ref.16. <sup>c</sup> The experimental electron mobilities were measured in different OFET devices, please refer to the references listed in brackets for the detailed device data.

## The electrostatic potential (ESP)

The electrostatic potential is given by the following expression:

$$V(\vec{r}) = \sum_A \frac{Z_A}{|\vec{r} - \vec{R}_A|} - \int \frac{\rho(\vec{r}')}{|\vec{r} - \vec{r}'|} d\vec{r}' \quad (\text{S1})$$

Where  $Z_A$  and  $\vec{R}_A$  are the charge and position of nucleus A, respectively, and  $\rho(\vec{r}')$  is the electron density at position  $\vec{r}'$ . The first term corresponds to the classical electrostatic potential of the nuclei and the second term corresponds to the quantum-mechanical electrostatic potential of the electrons. The sign of  $V(\vec{r})$  indicates the relative dominant contribution coming from the positive nuclei or the negative electrons. When  $V(\vec{r})$  mapped onto the molecular surface, namely  $\rho(\vec{r}') = 0.001$  au (electrons bohr<sup>-3</sup>) contour and thus labeled as  $V_s(r)$ , which could be used to analyze and predict the noncovalent interaction.<sup>17</sup>

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